NSN 5962-01-314-5854

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View Online at https://aerobasegroup.com/nsn/5962-01-314-5854

view Online at https://aerobasegroup.com/nsn/0302-01-014-0004
Body Length:
Between 1.350 inches and 1.560 inches
Body Width:
Between 0.480 inches and 0.610 inches
Body Height:
0.250 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
1260-01-208-6448 mast mounted si
Features Provided:
Static operation and high speed and w/enable and high reliability
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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